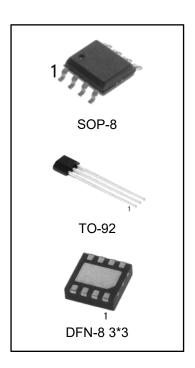


Description

The LM236 and LM336 are precision 5.0V regula- tor diodes. These voltage reference monolithic ICs operate like 5.0V zener diodes with a low temperature coefficient and a dynamic impedance of 0.6 Ω . A third pin enables adjusting the reference voltage and the temperature coefficient.

Features

- Adjustable 4V to 6V
- Low temperature coefficient
- Wide operating current of 600 µA to 10 mA
- 0.6 Λ dynamic impedance
- ± 1% initial tolerance available
- Guaranteed temperature stability
- Easily trimmed for minimum temperature drift
- Fast turn-on
- Three lead transistor package

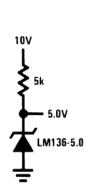


Ordering Information

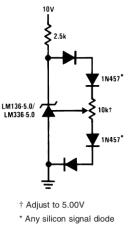
DEVICE	Package Type	MARKING	Packing	Packing Qty
LM236D-5.0RG	SOP-8	236-5.0	REEL	2500pcs/reel
LM236D-5.0RG4	SOP-8	236-5.0	REEL	4000pcs/reel
LM336D-5.0RG	SOP-8	336-5.0	REEL	2500pcs/reel
LM336D-5.0RG4	SOP-8	336-5.0	REEL	4000pcs/reel
LM236LP-5.0G	TO-92	LM236-5.0	BAG	1000pcs/box
LM336LP-5.0G	TO-92	LM336-5.0	BAG	1000pcs/box
LM236DQ-5.0RG	DFN-8 3*3	236-5.0	REEL	2500pcs/reel
LM336DQ-5.0RG	DFN-8 3*3	336-5.0	REEL	2500pcs/reel

Typical Applications

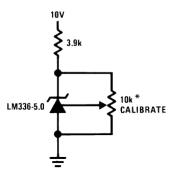




5.0V Reference with Minimum Temperature Coefficient



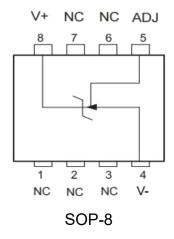
Trimmed 4V to 6V Reference with Temperature Coefficient Independent of Breakdown Voltage

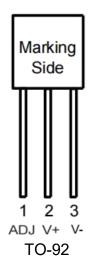


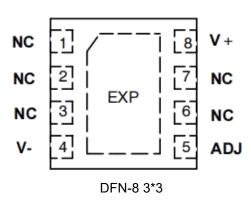
^{*} Does not affect temperature coefficient



Pin Connections







Absolute Maximum Ratings

Symbol	Parameter	LM336	Unit
	Current		
IRIF	Reverse	15	mA
	Forward	10	
Toper	Operating Free-air Temperature Range	LM336-5.0: 0 to +70	°C
Торсі	Operating Free-air remperature reange	LM236-5.0: -40 to +85	°C
T _{Stg}	Storage Temperature Range	-65 to +150	°C
T∟	Lead Temperature (Soldering, 10 seconds)	245	°C

Note: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured.

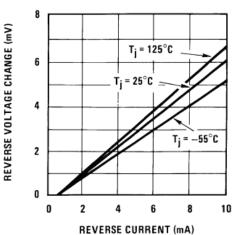
Electrical Characteristics

Symbol	Devemates	LN	11		
	Parameter Parameter	Min.	Тур.	Max.	Unit
VR	Reference Breakdown Voltage	4.9	5.0	5.1	V
	T_{amb} = +25°C, I_R = 1mA				
	Reverse Breakdown Voltage Change with Current				
ΔVR	600μA ≤ I _R ≤ 10mA	_	6	20	mV
[∆] vR	$T_{amb} = +25$ °C	_			IIIV
	T _{min.} ≤ T _{amb} ≤ T _{max.}				
	Reverse Dynamic Impedance (I _R = 1mA)		0.6	2.0	
Z _D	T _{amb} = +25°C f=100Hz	-			
	T _{min.} ≤ T _{amb} ≤ T _{max.}				
KVT	Temperature Stability ($V_R = 5.0V$, $I_R = 1mA$)	-	4	12	mV
K _{VH}	Long Term Stability (T _{amb} = +25°C ±0.1°C, I _R = 1mA)	-	20	-	ppm

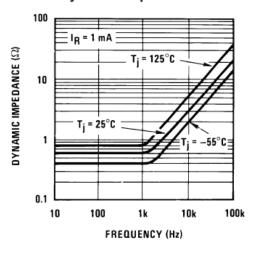


Typical Performance Characteristics

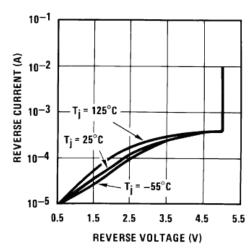
Reverse Voltage Change



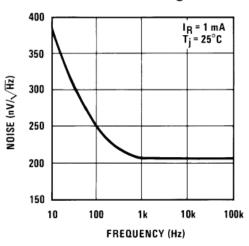
Dynamic Impedance



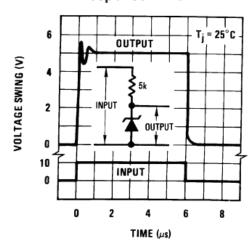
Reverse Characteristics



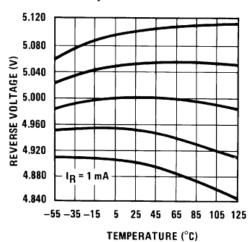
Zener Noise Voltage



Response Time

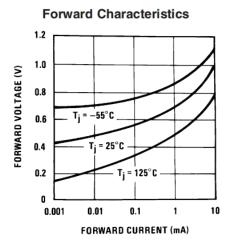


Temperature Drift





Typical Performance Characteristics (Continued)



Application Hints

The LMx36-5.0 series voltage references are much easier to use than ordinary zener diodes. Their low impedance and wide operating current range simplify biasing in almost any circuit. Further, either the breakdown voltage or the temperature coefficient can be adjusted to optimize circuit performance.

Figure 1 showsanLM336-5.0witha10kpotentiometerfor adjusting the reverse breakdown voltage. With the addition of R1 the breakdown voltage can be adjusted without affecting the temperature coefficient of the device. The adjustment range is usually sufficient to adjust for both the initial device tolerance and inaccuracies in buffer circuitry.

If minimum temperature coefficient is desired, four diodes can be added in series with the adjustment potentiometer as shown in Figure 2. When the device is adjusted to 5.00V the temperature coefficient is minimized. Almost any silicon signal diode can be used for this purpose such as a 1N914, 1N4148 or a 1N457. For proper temperature compensation the diodes should be in the same thermal environment as the LM336-5.0. It is usually sufficient to mount the diodes near the LM336-5.0 on the printed circuit board. The absolute resistance of the network is not critical and any value from 2k to 20k will work. Because of the wide adjustment range, fixed resistors should be connected in series with the pot to make pot setting less critical.

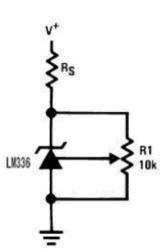


FIGURE1.LM336-5.0withPotforAdjustmentof
Breakdown Voltage (Trim Range = ±1.0V Typical)

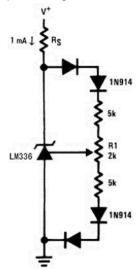
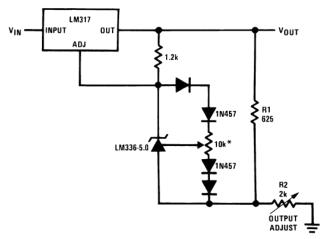


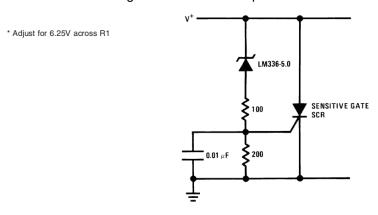
FIGURE 2. Temperature Coefficient Adjustment (Trim Range = ±0.5V Typical)



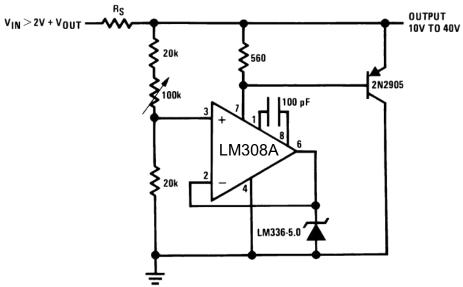
Typical Applications



Precision Power Regulator with Low Temperature Coefficient



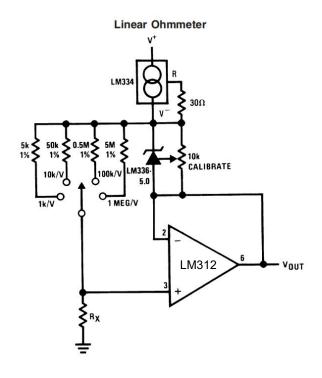
5V Crowbar



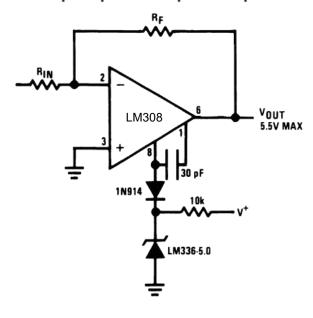
Adjustable Shunt Regulator



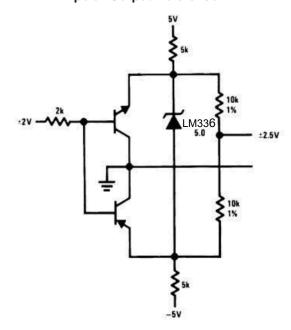
Typical Applications (Continued)



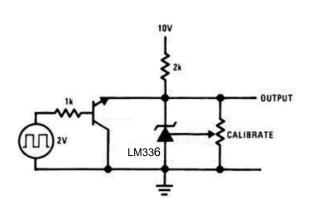
Op Amp with Output Clamped



Bipolar Output Reference



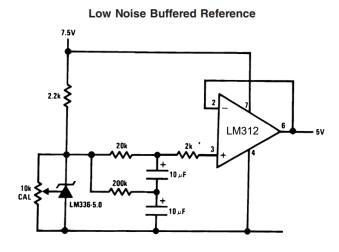
5.0V Square Wave Calibrator



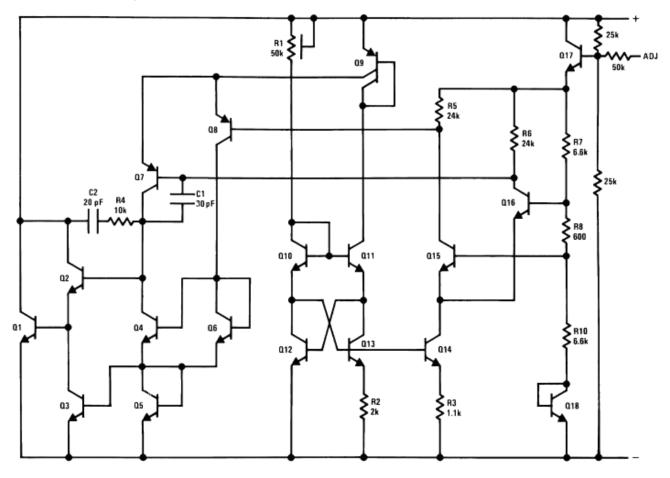


Typical Applications (Continued)

10V Buffered Reference 12V ≤ V_{IN} ≤ 36V 20k 11/k 20k 11/k LM308 6 10V 100 pF



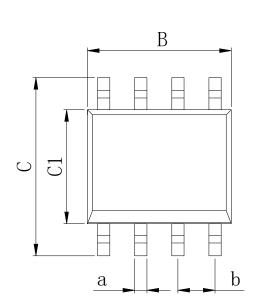
Schematic Diagram

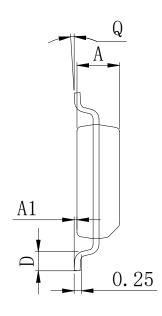




Physical Dimensions

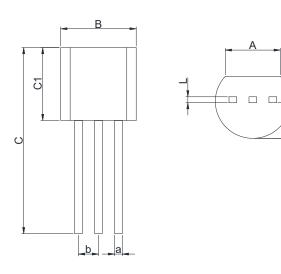
SOP-8





Dimensions In Millimeters(SOP-8)									
Symbol:	Α	A1	В	С	C1	D	Q	а	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1 27 DCC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	1.27 BSC

TO-92

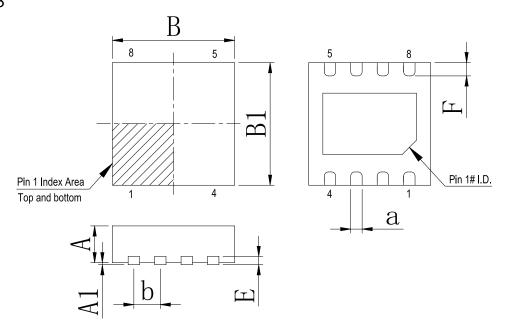


Dimensions In Millimeters(TO-92)									
Symbol:	А	В	С	C1	D	D1	L	а	b
Min:	3.43	4.44	11.2	4.32	3.17	2.03	0.33	0.40	1.27BSC
Max:	3.83	5.21	12.7	5.34	4.19	2.67	0.42	0.52	



Physical Dimensions

DFN-8 3*3



Dimensions In Millimeters(DFN-8 3*3)									
Symbol:	Α	A1	В	B1	Е	F	а	b	
Min:	0.85	0.00	2.90	2.90	0.20	0.30	0.20	0.05.000	
Max:	0.95	0.05	3.10	3.10	0.25	0.50	0.34	0.65 BSC	



Revision History

REVISION NUMBER	DATE	REVISION	PAGE
V1.0	2018-9	New	1-11
V1.1	2023-9	Update Lead Temperature、Add annotation for Maximum Ratings.	2





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